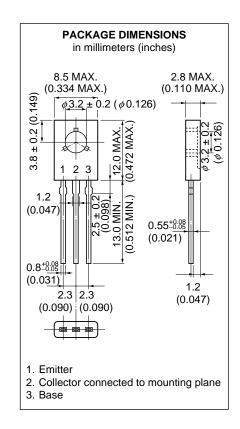
SILICON TRANSISTOR **2SB1657**

AUDIO FREQUENCY AMPLIFIER, SWITCHING PNP SILICON EPITAXIAL TRANSISTORS

FEATURES

NEC

• Low Vce(sat)		
$V_{CE(sat)} = -0.15 \text{ V Max} (@Ic/I_B = 0.5 \text{ A/z})$	25 mA)	
High DC Current Gain		
hfe = 150 to 600 (@Vce = -2.0 V, lc =	–0.5 A)	
ABSOLUTE MAXIMUM RATINGS		
Maximum Voltage and Current (TA = 25	°C)	
Collector to Base Voltage	Vсво	–30 V
Collector to Emitter Volteage	VCE0	–30 V
Emitter to Base Voltage	Veb0	-6.0 V
Collector Current (DC)	IC(DC)	–5.0 A
Collector Current (Pulse)*	C(Pulse)	-8.0 A
Base Current (DC)	B(DC)	-1.0 A
* PW \leq 10ms, Duty Cycle \leq 10 %		
Maximum Power Dissipation		
Total Power Dissipation (Tc = 25 °C)	Р⊤	10 W



ELECTRICAL CHARACTERISTICS (TA = 25 °C)

Ρт

Tj

Tstg

Total Power Dissipation (T_A = 25 °C)

Maximum Temperature Junction Temperature

Storage Temperature

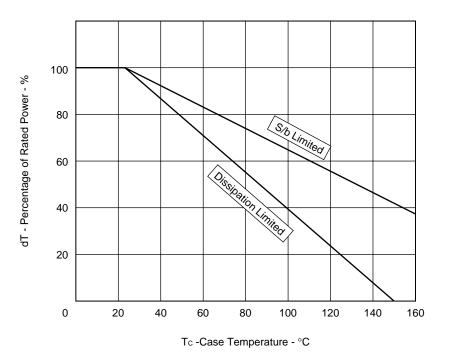
characteristics	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNIT
Collector Cutoff Currnet	Ісво	$V_{CB} = -30 V$, Ie = 0			-100	nA
Emitter Cutoff Current	Іево	$V_{EB} = -6.0 \text{ V}, \text{ Ic} = 0$			-100	nA
DC Current Gain	hfe1	$V_{CE} = -2.0 V$, Ic = -0.5 A	150		600	_
DC Current Gain	hfe2	$V_{CE} = -2.0 \text{ V}, \text{ Ic} = -3.0 \text{ A}$	70			_
Collector Saturation Voltage	VCE(sat)1	$Ic = -0.5 A$, $I_B = -25 mA$		-0.08	-0.15	V
Collector Saturation Voltage	V _{CE(sat)2}	$Ic = -1.0 A$, $I_B = -50 mA$		-0.13	-0.25	V
Collector Saturation Voltage	V _{CE(sat)3}	Ic = -2.0 A, I _B = -100 mA		-0.24	-0.40	V
Collector Saturation Voltage	VCE(sat)4	Ic = -3.0 V, I _B = -75 mA		-0.46	-1.0	V
Base Saturation Voltage	VBE(sat)	$Ic = -1.0 A$, $I_B = -50 mA$		-0.83	-1.50	V
Gain Bandwidth Product	f⊤	V_{CE} = -10 V, Ie = -50 mA		75		MHz
Output Capacitance	Cob	$V_{CB} = -10 V$, $I_E = 0$, $f = 1 MHz$		60		pF

1.0 W

150 °C

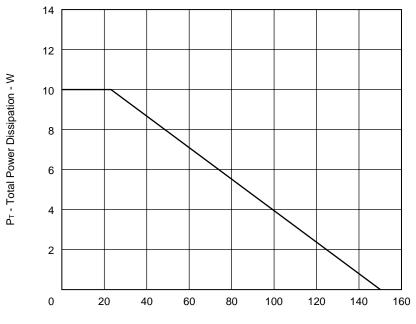
–55 to 150 °C

The information in this document is subject to change without notice.



DERATING FACTOR OF FORWARD BIAS SAFE OPERATING AREA

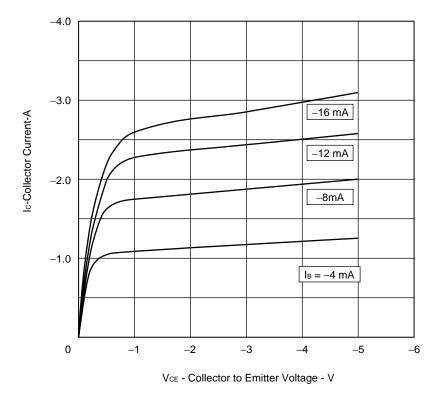




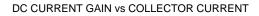
Tc -Case Temperature - °C

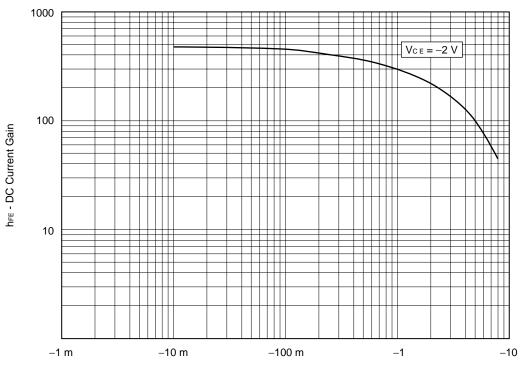
-100 10, may Ic - Collector Current - A C(pulse) -10 Ins. A Dissipation Linnier TO MS IC(DC) -1 Solimited Tc = 25 °C Single Pulse -0.1 -0.1 -1 -10 -100 VCE - Collector to Emitter Voltage - V

FORWARD BIAS SAFE OPERATING AREA

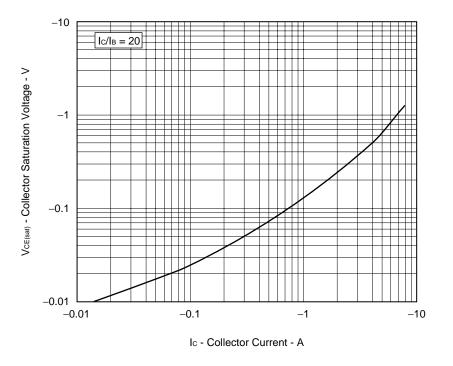


COLLECTOR TO EMITTER VOLTAGE vs COLLECTOR CURRENT



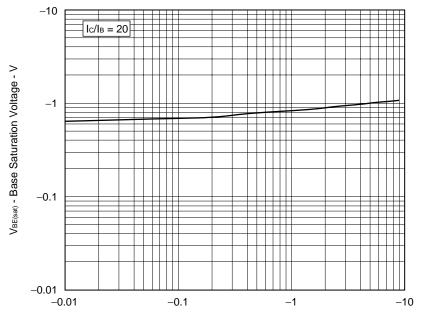


Ic - Collector Current - A

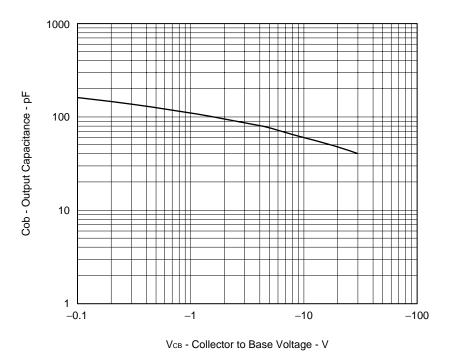


COLLECTOR SATURATION VOLTAGE vs COLLECTOR CURRENT





Ic - Collector Current - A



OUTPUT CAPACITANCE vs COLLECTOR TO BASE VOLTAGE

REFERENCE

Document Name	Document No.	
NEC semiconductor device reliability/quality control system	TEI-1202	
Quality grade on NEC semiconductor devices	IEI-1209	
Semiconductor device mounting technology manual	C10535E	
Semiconductor device package manual	C10943X	
Guide to quality assurance for semiconductor devices	MEI-1202	
Semiconductor selection guide	X10679E	

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- Special: Transportation equipment (automobiles, trains, ships, etc.), traffic control systems, anti-disaster systems, anti-crime systems, safety equipment and medical equipment (not specifically designed for life support)
- Specific: Aircrafts, aerospace equipment, submersible repeaters, nuclear reactor control systems, life support systems or medical equipment for life support, etc.

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Anti-radioactive design is not implemented in this product.